1200V/5A Silicon Carbide Power Schottky Barrier Diode

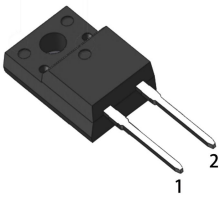
Features

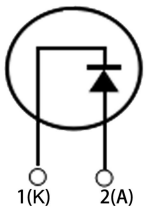
- Zero reverse recovery current
- Zero forward recovery voltage
- Temperature independent switching behavior
- High temperature operation
- High frequency operation

Key Characteristics		
V_{RRM}	1200	V
I_F, $T_c \leqslant 145℃$	5	A
Q_C	36	nC

Benefits

- Unipolar rectifier
- Substantially reduced switching losses
- No thermal run-away with parallel devices
- Reduced heat sink requirements





Applications

- SMPS, e.g., CCM PFC;
- Motor drives, Solar application, UPS, Wind turbine, Rail traction, EV/HEV

REACH SVHC

Halogen-Free

RoHS

Part No.	Package Type	Marking
G3S12005H	TO-220F	G3S12005H

Maximum Ratings

Parameter	Symbol	Test Condition	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}		1200	V
Surge Peak Reverse Voltage	V_{RSM}		1200	
DC Blocking Voltage	V_{DC}		1200	
Continuous Forward Current	I_F	T_C=25℃ T_C=125℃ T_C=145℃	12.5 6.7 5	A
Repetitive Peak Forward Surge Current	I_{FRM}	T_C=25℃, tp=10ms， Half Sine Wave，D=0.3	30	A
Non-repetitive Peak Forward Surge Current	I_{FSM}	T_C=25℃, tp=10ms， Half Sine Wave	100	A
Power Dissipation	P_{TOT}	T_C=25℃	50	W
		T_C=110℃	22	W
Operating Junction	T_j		-55℃ to 175℃	℃
Storage Temperature	T_{stg}		-55℃ to 175℃	℃
Mounting Torque		M3 Screw 6-32 Screw	1 8.8	Nm lbf-in

Thermal Characteristic

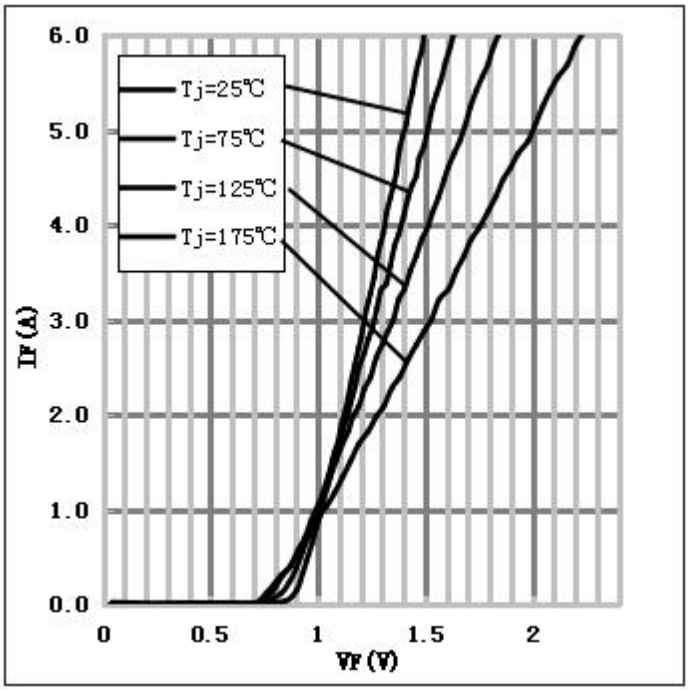
Parameter	Symbol	Test Condition	Value	Unit
			Typ.	
Thermal resistance from junction to case	$R_{th\ JC}$		2.99	℃/W

Electrical Characteristics

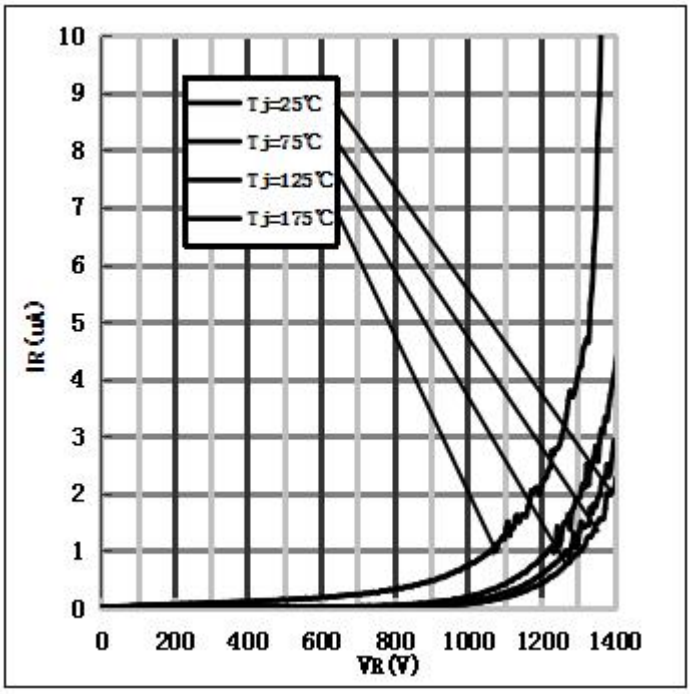
Parameter	Symbol	Test Conditions	Numerical		Unit
			Typ.	Max.	
Forward Voltage	V_F	I_F=5A, T_j=25℃	1.46	1.7	V
		I_F=5A, T_j=175℃	1.95	2.5	
Reverse Current	I_R	V_R=1200V, T_j=25℃	0.15	50	μA
		V_R=1200V, T_j=175℃	0.35	100	
Total Capacitive Charge	Q_C	V_R=800V, T_j=150℃ $Qc = \int_0^{VR} C(V)dV$	36	-	nC
Total Capacitance	C	V_R=0V, T_j=25℃, f=1MHZ	475	510	pF
		V_R=400V, T_j=25℃, f=1MHZ	34	44	
		V_R=800V, T_j=25℃, f=1MHZ	33	40	

Performance Graphs

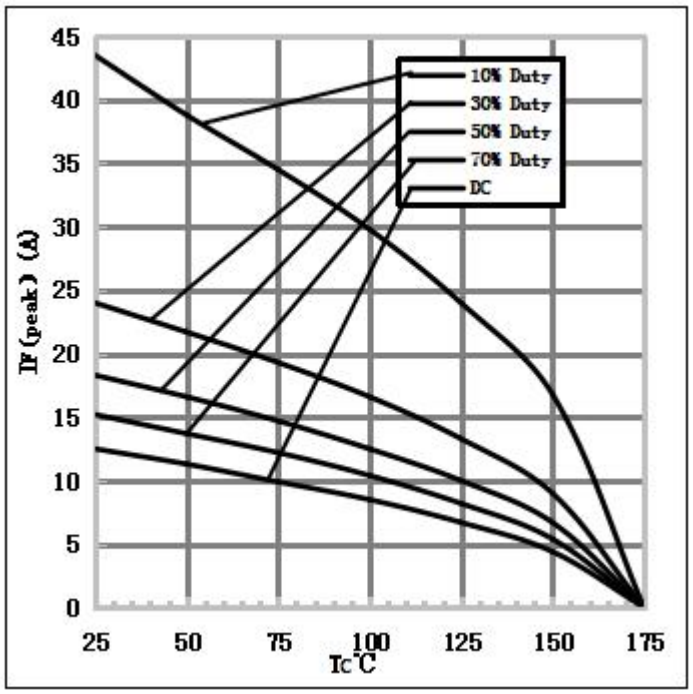
1) Forward IV characteristics as a function of Tj :



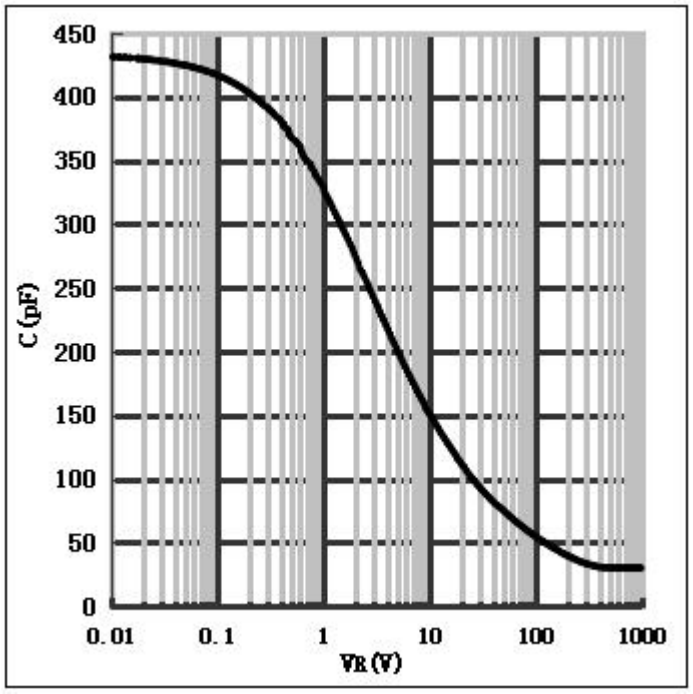
2) Reverse IV characteristics as a function of Tj :



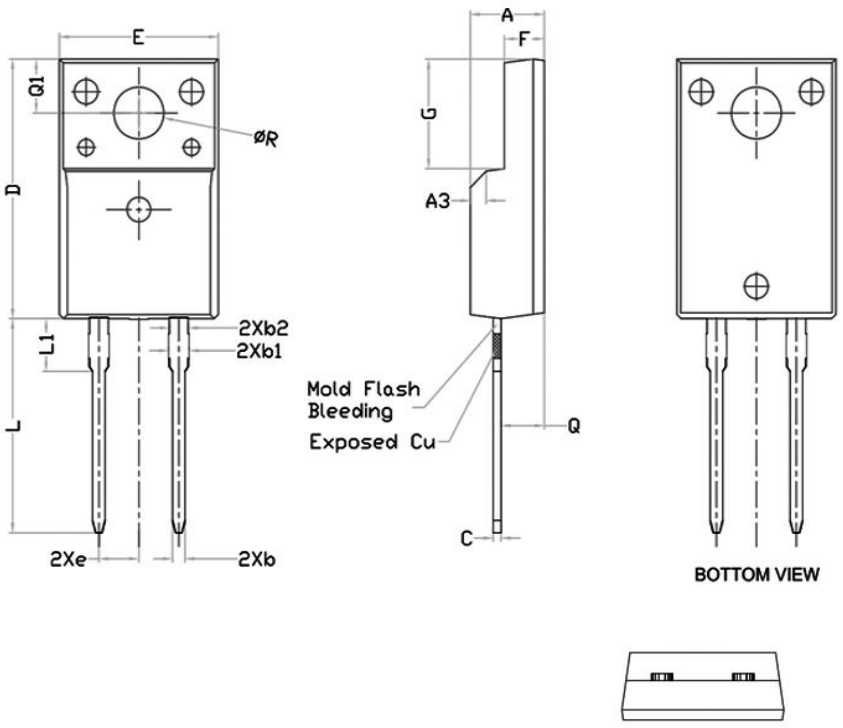
3) Current Derating:



4) Capacitance vs. reverse voltage:



Package TO-220F



单位：mm

SYMBOL	DIMENSIONS		
	Min.	Nom.	Max.
A	4.60	4.70	4.80
b	0.70	0.80	0.91
b1	1.20	1.30	1.47
b2	1.10	1.20	1.30
C	0.45	0.50	0.63
D	15.80	15.87	15.97
e		2.54	
E	10.00	10.10	10.30
F	2.44	2.54	2.64
G	6.50	6.70	6.90
L	12.90	13.10	13.30
L1	3.13	3.23	3.33
Q	2.65	2.75	2.85
Q1	3.20	3.30	3.40
ΦR	3.08	3.18	3.28

Note:

1. All Dimension Are In mm.
2. Package Body Sizes Exclude Mold Flash And Burrs Mold Flash Should Be Less Than 6 Mil.

Note: The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC(RoHS2). RoHS Certification and other certifications can be obtained from GPT sales representatives or GPT website: http://globalpowertech.cn/English/index.asp

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